

RF LDMOS Wideband Integrated Power Amplifier

The MHVIC2114NR2 wideband integrated circuit is designed for base station applications. It uses Freescale's newest High Voltage (26 to 28 Volts) LDMOS IC technology and integrates a multi-stage structure. Its wideband On-Chip matching design makes it usable from 1600 to 2600 MHz. The linearity performances cover all modulation formats for cellular applications: CDMA and W-CDMA. The device is in a PFP-16 flat pack package that provides excellent thermal performance through a solderable backside contact.

Final Application

- Typical Two-Tone Performance: $V_{DD} = 27$ Volts, $I_{DQ1} = 95$ mA, $I_{DQ2} = 204$ mA, $I_{DQ3} = 111$ mA, $P_{out} = 15$ Watts PEP, Full Frequency Band
Power Gain — 32 dB
IMD — -30 dBc

Driver Application

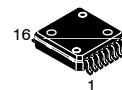
- Typical Single-Channel W-CDMA Performance: $V_{DD} = 27$ Volts, $I_{DQ1} = 96$ mA, $I_{DQ2} = 204$ mA, $I_{DQ3} = 111$ mA, $P_{out} = 23$ dBm, 2110-2170 MHz, 3GPP Test Model 1, Measured in 3.84 MHz BW @ 5 MHz Offset, 64 DTCH, PAR = 8.5 dB @ 0.01% Probability on CCDF.
Power Gain — 32 dB
ACPR — -58 dBc
- P1dB = 14 Watts, Gain Flatness = 0.2 dB from 2110 to 2170 MHz
- Capable of Handling 3:1 VSWR, @ 27 Vdc, 2140 MHz, 15 Watts CW Output Power

Features

- Characterized with Series Equivalent Large-Signal Impedance Parameters and Common Source Scattering Parameters
- On-Chip Matching (50 Ohm Input, DC Blocked, >5 Ohm Output)
- Integrated Temperature Compensation with Enable/Disable Function
- Integrated ESD Protection
- RoHS Compliant
- In Tape and Reel. R2 Suffix = 1,500 Units per 16 mm, 13 inch Reel.

MHVIC2114NR2

**2100 MHz, 27 V, 23 dBm
SINGLE W-CDMA
RF LDMOS WIDEBAND
INTEGRATED POWER AMPLIFIER**



**CASE 978-03
PFP-16**

LIFETIME BUY

LAST SHIP 30 JUN 12
LAST ORDER 1 JUL 11

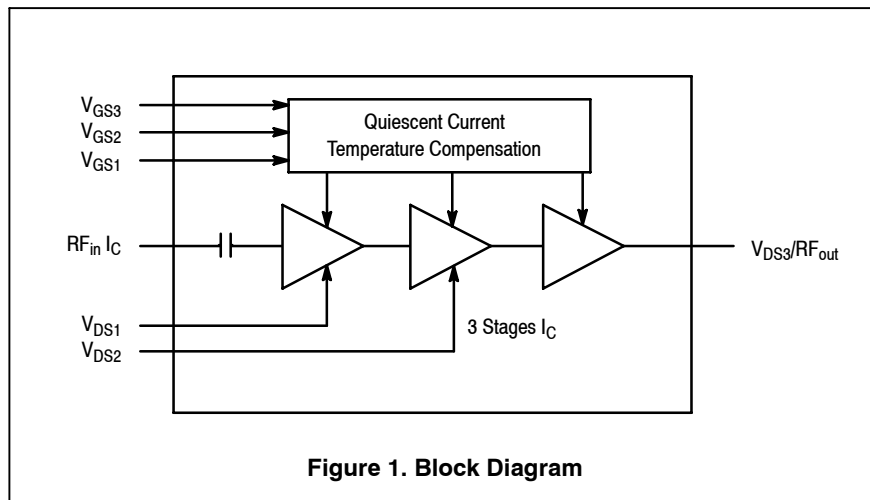


Figure 1. Block Diagram

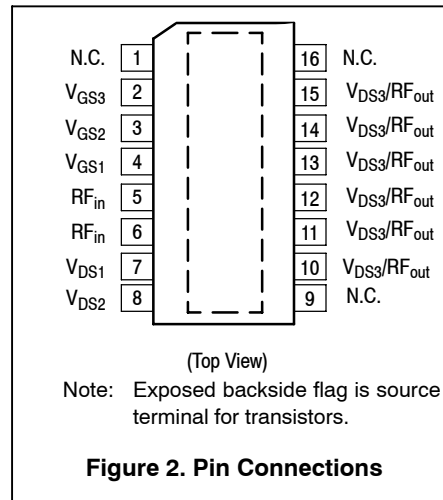


Figure 2. Pin Connections

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-0.5, +65	Vdc
Gate-Source Voltage	V_{GS}	-0.5, +15	Vdc
Storage Temperature Range	T_{stg}	- 65 to +150	°C
Operating Junction Temperature	T_J	150	°C
Input Power	P_{in}	5	dBm

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$		°C/W
Driver Application ($P_{out} = +0.2$ W CW)	Stage 1, 27 Vdc, $I_{DQ1} = 96$ mA Stage 2, 27 Vdc, $I_{DQ2} = 204$ mA Stage 3, 27 Vdc, $I_{DQ3} = 111$ mA	11.5 7.52 5.52	

Table 3. ESD Protection Characteristics

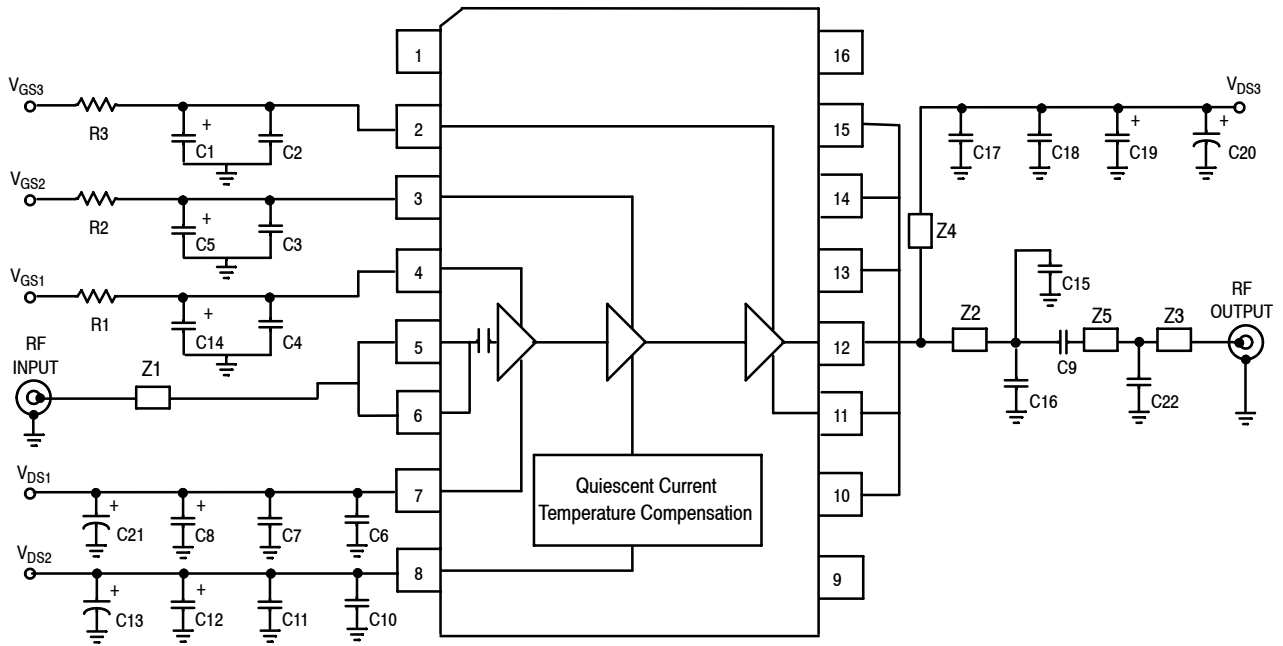
Test Methodology	Class
Human Body Model (per JESD22-A114)	0 (Minimum)
Machine Model (per EIA/JESD22-A115)	A (Minimum)
Charge Device Model (per JESD22-C101)	II (Minimum)

Table 4. Moisture Sensitivity Level

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD 22-A113, IPC/JEDEC J-STD-020	3	260	°C

Table 5. Electrical Characteristics ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
W-CDMA Characteristics (In Freescale Test Fixture, 50 ohm system) $V_{DD} = 27$ Vdc, $I_{DQ1} = 96$ mA, $I_{DQ2} = 204$ mA, $I_{DQ3} = 111$ mA, $P_{out} = 23$ dBm, 2110–2170 MHz, Single-Carrier W-CDMA, 3.84 MHz Channel Bandwidth Carrier. ACPR measured in 3.84 MHz Channel Bandwidth @ ± 5 MHz Offset. PAR = 8.5 dB @ 0.01% Probability on CCDF.					
Power Gain	G_{ps}	29	32	36	dB
Gain Flatness	G_F	—	0.3	0.5	dB
Input Return Loss	IRL	—	-13	-10	dB
Adjacent Channel Power Ratio	ACPR	—	-60	-57	dBc
Group Delay	Delay	—	1.7	—	ns
Phase Linearity	—	—	0.2	—	°

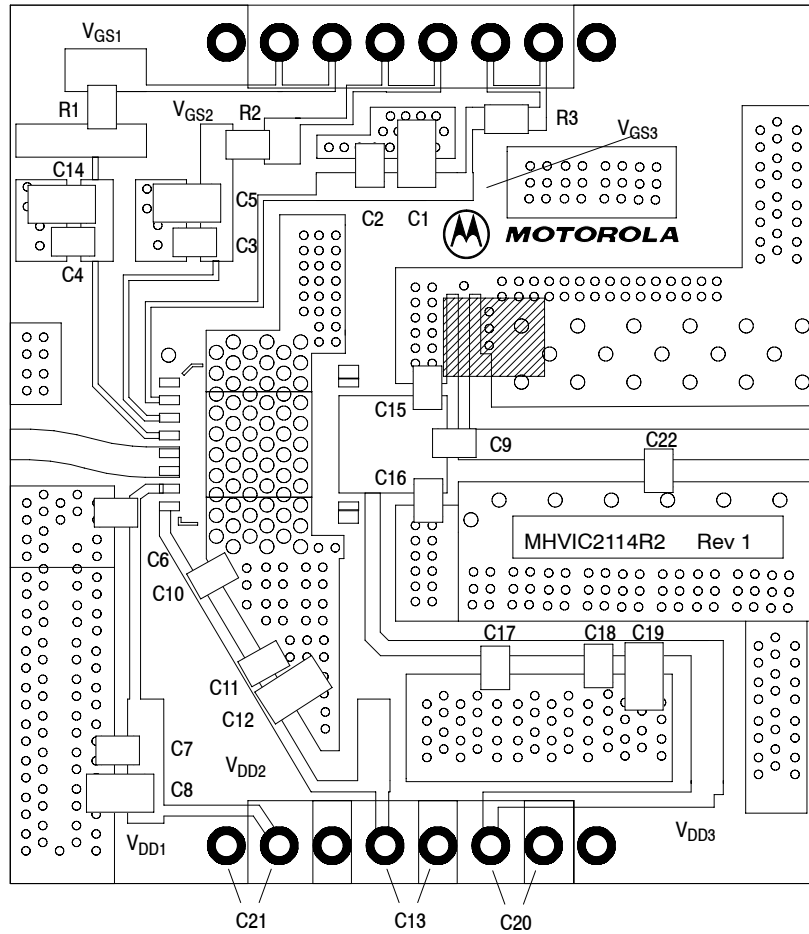


- Z1 0.323" x .055" 50 Ω Microstrip
- Z2 0.196" x .176" Microstrip
- Z3 0.286" x .055" Microstrip
- Z4 0.150" x .018" Microstrip
- Z5 0.363" x .055" Microstrip
- PCB Arlon, 0.021", $\epsilon_r = 2.55$

Figure 3. MHVIC2114NR2 Test Circuit Schematic

Table 6. MHVIC2114NR2 Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C5, C8, C12, C14, C19	1 μF Tantalum Chip Capacitors	TAJA105K035R	Kemet
C2, C3, C4, C7, C11, C18	0.01 μF Chip Capacitors	0805C103K5RACTR	Vishay
C6, C10, C17	6.8 pF Chip Capacitors (ACCU-P)	AVX08051J6R8BBT	AVX
C9	1.5 pF Chip Capacitor (ACCU-P)	AVX08051J1R5BBT	AVX
C15, C16	2.2 pF Chip Capacitors (ACCU-P)	AVX08051J2R2BBT	AVX
C22	1.0 pF Chip Capacitor (ACCU-P)	AVX08051J1R0BBT	AVX
C13, C20, C21	330 μF Electrolytic Capacitors	MCR35V337M10X16	Multicomp
R1, R2, R3	1 kΩ Chip Resistors (0805)	P1.00KCT-ND	Panasonic



Freescale has begun the transition of marking Printed Circuit Boards (PCBs) with the Freescale Semiconductor signature/logo. PCBs may have either Motorola or Freescale markings during the transition period. These changes will have no impact on form, fit or function of the current product.

Figure 4. MHVIC2114NR2 Test Circuit Component Layout

TYPICAL CHARACTERISTICS

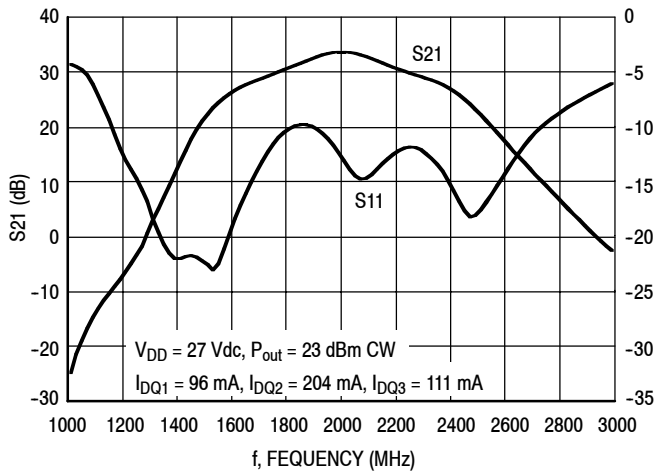


Figure 5. Broadband Frequency Response

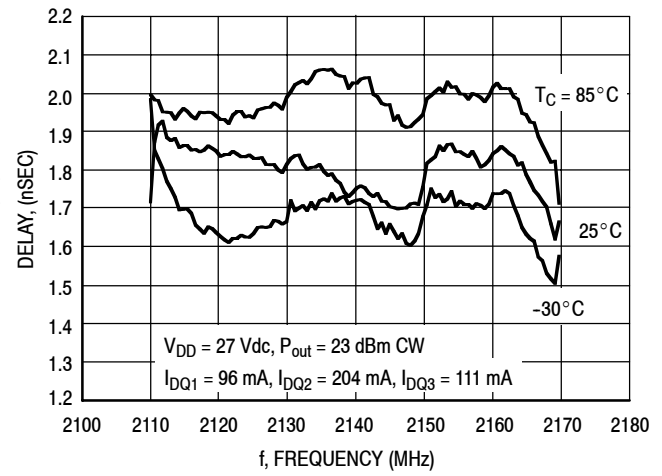


Figure 6. Delay versus Frequency

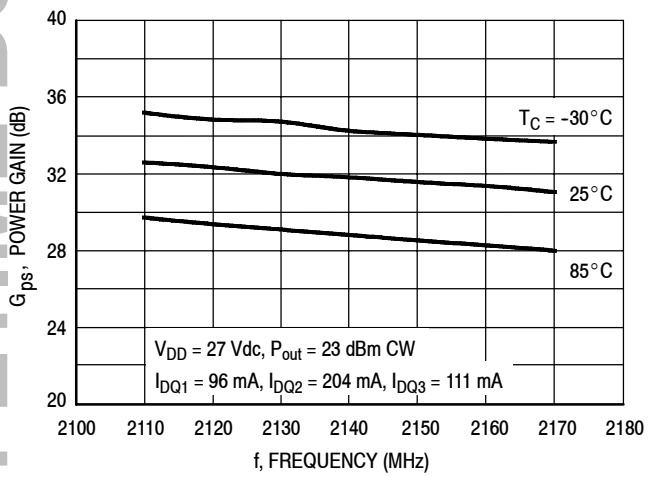


Figure 7. Power Gain versus Frequency

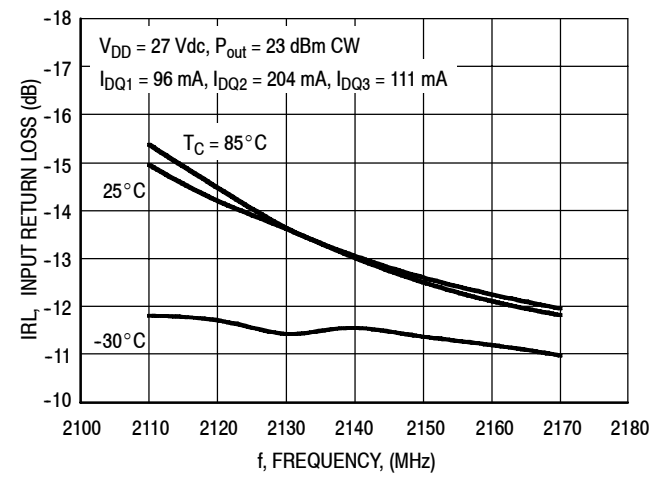


Figure 8. Input Return Loss versus Frequency

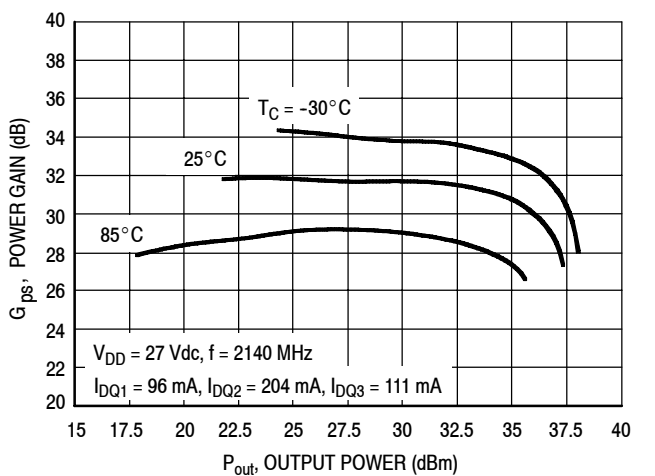


Figure 9. Power Gain versus Output Power

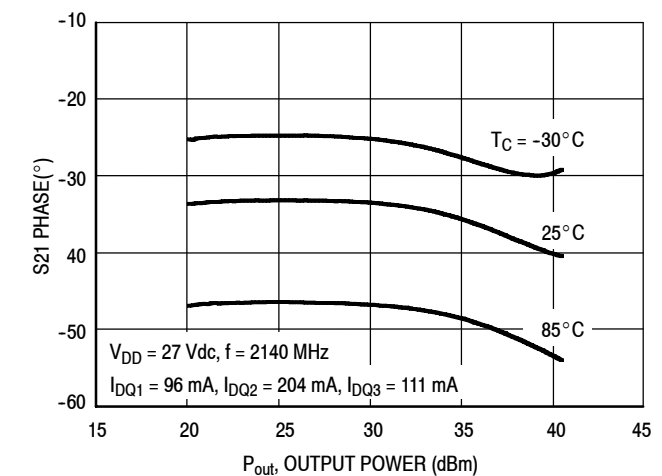


Figure 10. S21 Phase versus Output Power

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TYPICAL CHARACTERISTICS

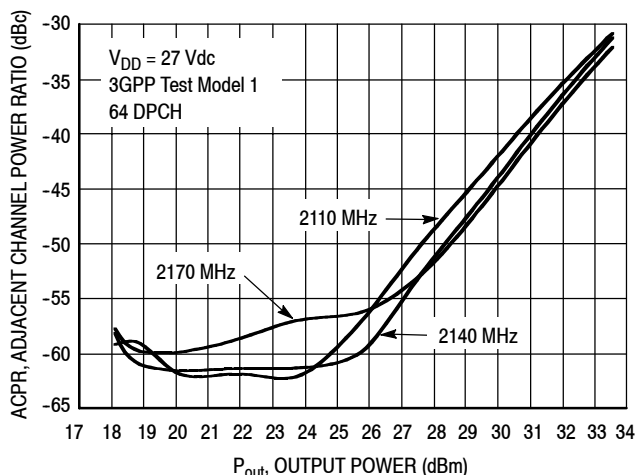


Figure 11. W-CDMA ACPR versus Output Power

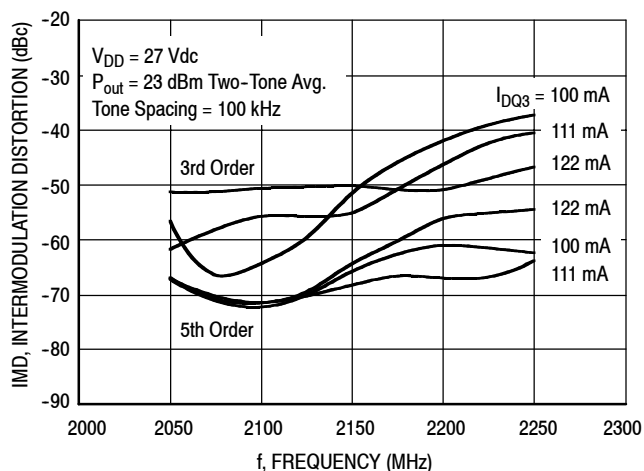


Figure 12. Two-Tone Intermodulation Distortion Products versus Frequency

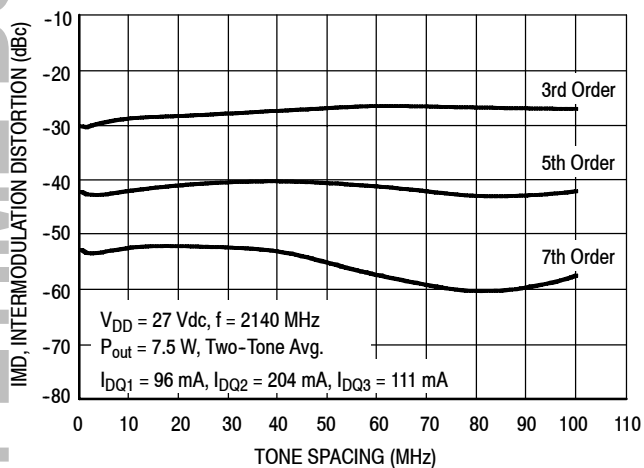


Figure 13. Two-Tone Intermodulation Distortion Products versus Tone Spacing

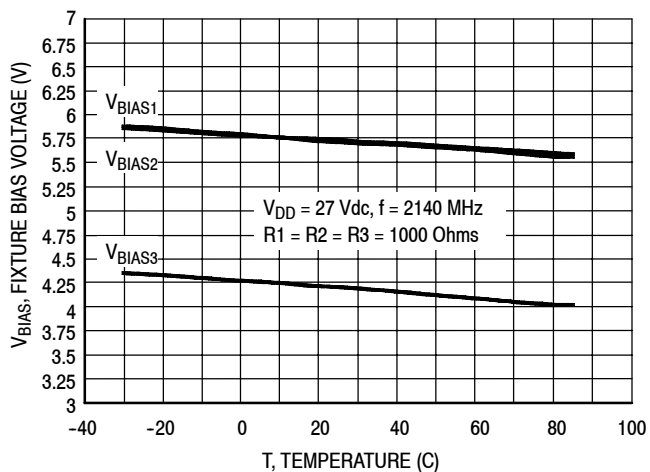


Figure 14. Fixture Bias versus Temperature

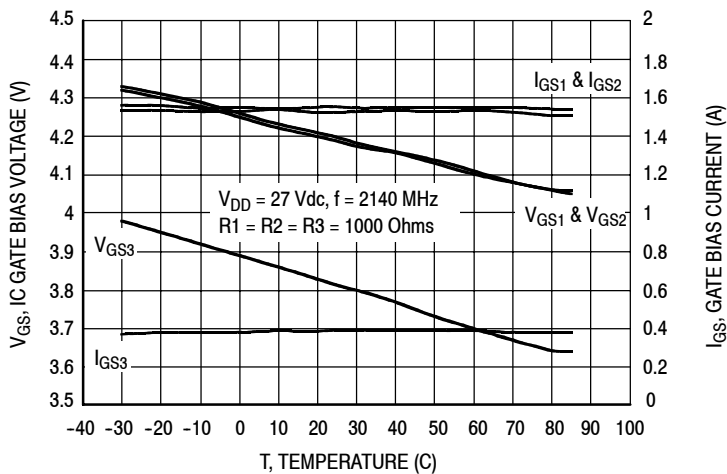
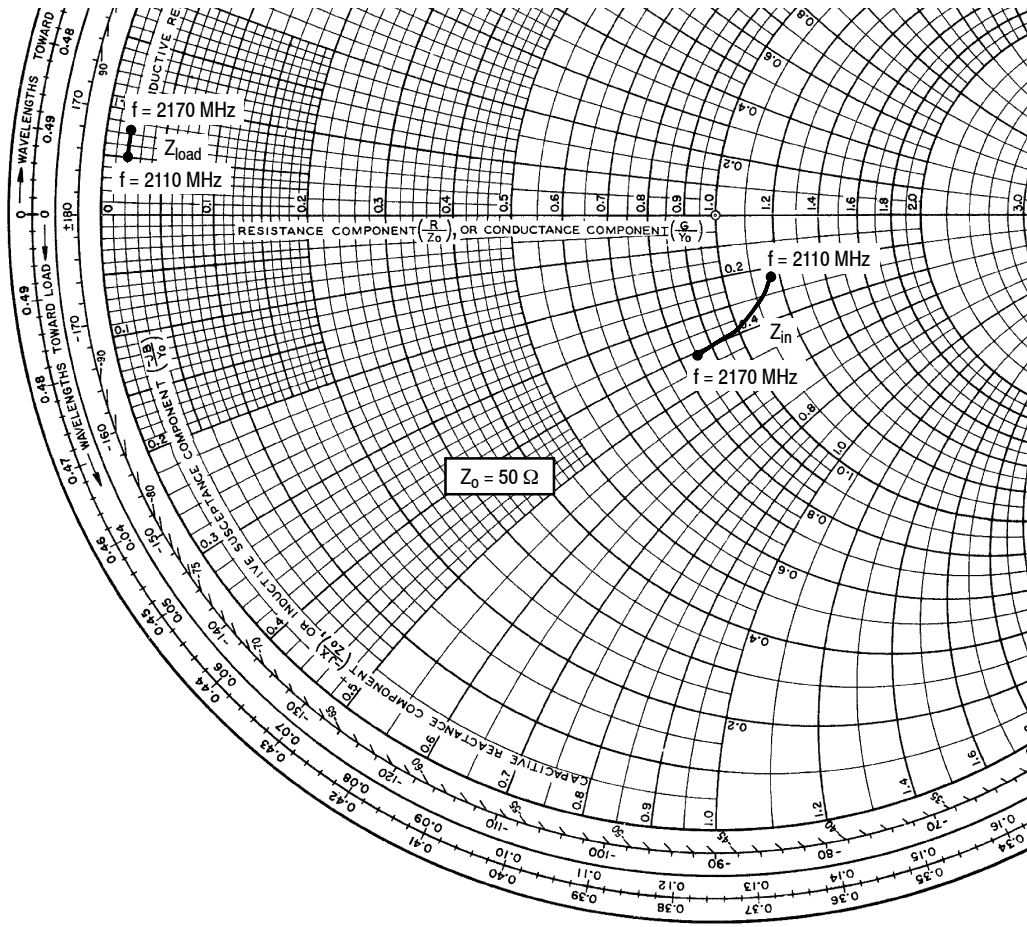


Figure 15. Gate Bias versus Temperature

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$V_{DD} = 27 \text{ Vdc}$, $I_{DQ1} = 96 \text{ mA}$, $I_{DQ2} = 204 \text{ mA}$, $I_{DQ3} = 111 \text{ mA}$, $P_{out} = 23 \text{ dBm}$

f MHz	Z_{in} Ω	Z_{load} Ω
2110	$57.9 - j12.1$	$1.1 + j2.7$
2140	$50.6 - j18.9$	$1.1 + j3.4$
2170	$42.3 - j21.1$	$1.2 + j3.7$

Z_{in} = Device input impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

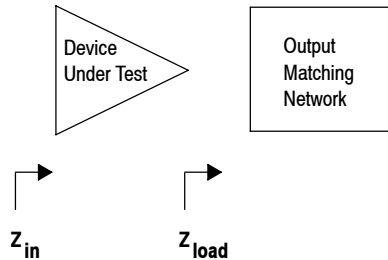


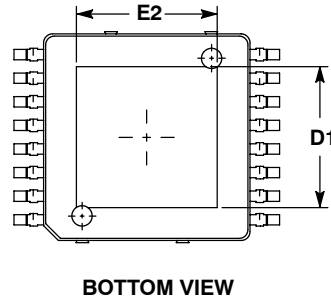
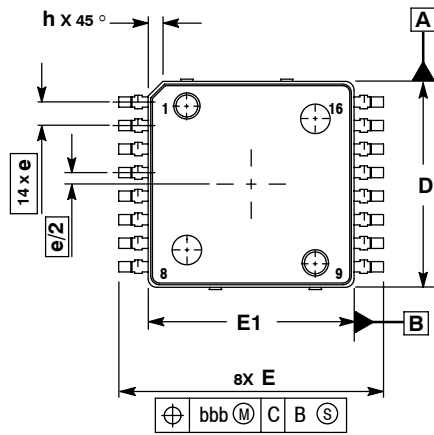
Figure 16. Series Equivalent Input and Load Impedance

NOTES

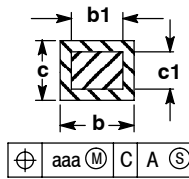
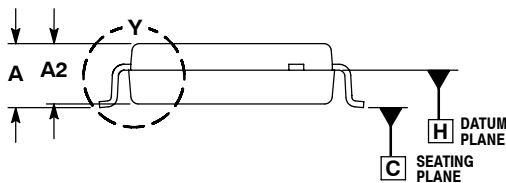
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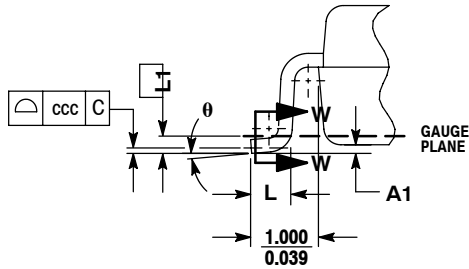
PACKAGE DIMENSIONS



BOTTOM VIEW



SECT W-W



DETAIL Y

NOTES:

1. CONTROLLING DIMENSION: MILLIMETER.
2. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DATUM PLANE -H- IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 PER SIDE. DIMENSIONS D AND E1 DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION IS 0.127 TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-.

DIM	MILLIMETERS	
	MIN	MAX
A	2.000	2.300
A1	0.025	0.100
A2	1.950	2.100
D	6.950	7.100
D1	4.372	5.180
E	8.850	9.150
E1	6.950	7.100
E2	4.372	5.180
L	0.466	0.720
L1	0.250 BSC	
b	0.300	0.432
b1	0.300	0.375
c	0.180	0.279
c1	0.180	0.230
e	0.800 BSC	
h	---	0.600
θ	0°	7°
aaa	0.200	
bbb	0.200	
ccc	0.100	

**CASE 978-03
ISSUE C
PFP-16**

How to Reach Us:

Home Page:

www.freescale.com

E-mail:

support@freescale.com

USA/Europe or Locations Not Listed:

Freescale Semiconductor
 Technical Information Center, CH370
 1300 N. Alma School Road
 Chandler, Arizona 85224
 +1-800-521-6274 or +1-480-768-2130
support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
 Technical Information Center
 Schatzbogen 7
 81829 Muenchen, Germany
 +44 1296 380 456 (English)
 +46 8 52200080 (English)
 +49 89 92103 559 (German)
 +33 1 69 35 48 48 (French)
support@freescale.com

Japan:

Freescale Semiconductor Japan Ltd.
 Headquarters
 ARCO Tower 15F
 1-8-1, Shimo-Meguro, Meguro-ku,
 Tokyo 153-0064
 Japan
 0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
 Technical Information Center
 2 Dai King Street
 Tai Po Industrial Estate
 Tai Po, N.T., Hong Kong
 +800 2666 8080
support.asia@freescale.com

For Literature Requests Only:

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